CD74HC652, CD74HCT652

High-Speed CMOS Logic
Octal-Bus Transceiver/Registers, Three-State

February 1998

Features

- CD74HC652, CD74HCT652 . . . . Non-Inverting
- Independent Registers for A and B Buses
- Three-State Outputs
- Drives 15 LSTTL Loads
- Typical Propagation Delay = 12ns at V_{CC} = 5V, C_L = 15pF
- Fanout (Over Temperature Range)
  - Standard Outputs . . . . 10 LSTTL Loads
  - Bus Driver Outputs . . . . 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- Alternate Source is Philips
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility, V_{IL} = 0.8V (Max), V_{IH} = 2V (Min)
  - CMOS Input Compatibility, $I_I \leq 1\mu A$ at V_{OL}, V_{OH}

Pinout

**CD74HC652, CD74HCT652
(PDIP, SOIC)
TOP VIEW**

```
       CAB  [1      24]  VCC
       SAB  [2      23]  CBA
      OEAB  [3      22]  SBA
        A0  [4      21]  OEBA
        A1  [5      20]  B0
        A2  [6      19]  B1
        A3  [7      18]  B2
        A4  [8      17]  B3
        A5  [9      16]  B4
        A6  [10     15]  B5
        A7  [11     14]  B6
       GND  [12     13]  B7
```

Description

The Harris CD74HC652 and CD74HCT652 three-state, octal-bus transceiver/registers use silicon-gate CMOS technology to achieve operating speeds similar to LSTTL with the low power consumption of standard CMOS integrated circuits. The CD74HC652 and CD74HCT652 have non-inverting outputs. These devices consists of bus transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Output Enables OE_{AB} and OE_{BA} are provided to control the transceiver functions. SAB and SBA control pins are provided to select whether real-time or stored data is transferred. The circuitry used for select control will eliminate the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. A LOW input level selects real-time data, and a HIGH selects stored data. The following examples demonstrates the four fundamentals bus-management functions that can be performed with the octal-bus transceivers and registers.

Data on the A or B data bus, or both, can be stored in the internal D flip-flops by low-to-high transitions at the appropriate clock pins (CAB or CBA) regardless of the select of the control pins. When SAB and SBA are in the real-time transfer mode, it is also possible to store data without using the D-type flip-flops by simultaneously enabling OE_{AB} and OE_{BA}. In this configuration, each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines will remain at its last state.
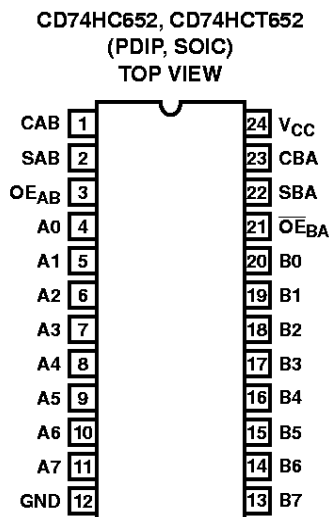
Ordering Information

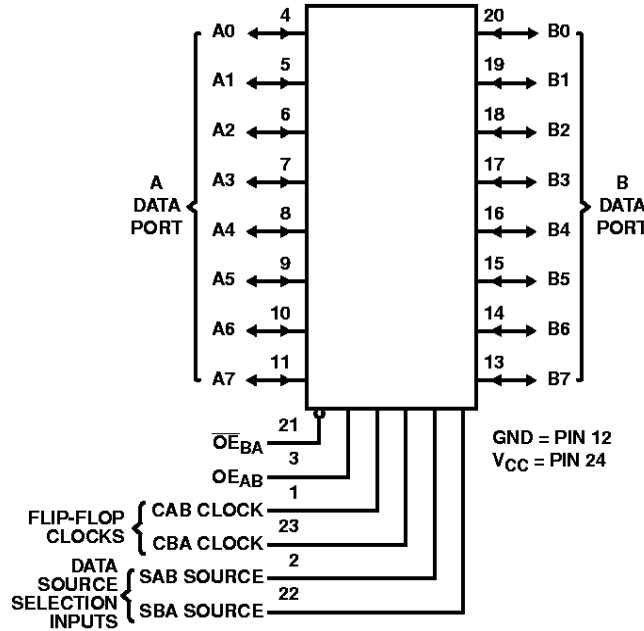| PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CD74HC652EN	-55 to 125	24 Ld PDIP	E24.3
CD74HCT652M	-55 to 125	24 Ld SOIC	M24.3

NOTES:

1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.

2. Wafer and die is available which meets all electrical specifications. Please contact your local sales office or Harris customer service for ordering information.

File Number **2229.2**

Functional Diagram

A DATA PORT

Pin	Signal
4	A0
5	A1
6	A2
7	A3
8	A4
9	A5
10	A6
11	A7

B DATA PORT

Pin	Signal
20	B0
19	B1
18	B2
17	B3
16	B4
15	B5
14	B6
13	B7

$\overline{OE}_{BA}$ — 21
OE_{AB} — 3

FLIP-FLOP CLOCKS { CAB CLOCK — 1 ; CBA CLOCK — 23 }

DATA SOURCE SELECTION INPUTS { SAB SOURCE — 2 ; SBA SOURCE — 22 }

GND = PIN 12
V_{CC} = PIN 24

FUNCTION TABLE

INPUTS						DATA I/O		OPERATION OR FUNCTION	
OE_{AB}	$\overline{OE}_{BA}$	CAB	CBA	SAB	SBA	A0 THRU A7	B0 THRU B7	651	652
L	H	H or L	H or L	X	X	Input	Input	Isolation (Note 3)	Isolation (Note 3)
L	H	↑	↑	X	X			Store A and B Data	Store A and B Data
X	H	↑	H or L	X	X	Input	Unspecified (Note 4)	Store A, Hold B	Store A, Hold B
H	H	↑	↑	X (Note 5)	X	Input	Output	Store A in Both Registers	Store A in Both Registers
L	X	H or L	↑	X	X	Unspecified (Note 4)	Input	Hold A, Store B	Hold A, Store B
L	L	↑	↑	X	X (Note 5)	Output	Input	Store B in Both Registers	Store B in Both Registers
L	L	X	X	X	L	Output	Input	Real-Time B Data to A Bus	Real-Time B Data to A Bus
L	L	X	H or L	X	H			Stored B Data to A Bus	Stored B Data to A Bus
H	H	X	X	L	X	Input	Output	Real-Time A Data to B Bus	Real-Time A Data to B Bus
H	H	H or L	X	H	X			Stored A Data to B Bus	Stored A Data to B Bus
H	L	H or L	H or L	H	H	Output	Output	Stored A Data to B Bus and	Stored A Data to B Bus
								Stored B Data to A Bus	Stored B Data to A Bus

NOTES:

3. To prevent excess currents in the High-Z (isolation) modes, all I/O terminals should be terminated with 10kΩ to 1MΩ resistors.

4. The data output functions may be enabled or disabled by various signals at the OE_{AB} or $\overline{OE}_{BA}$ inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs.

5. Select Control = L: Clocks can occur simultaneously.
   Select Control = H: Clocks must be staggered in order to load both registers.

FIGURE 1. LOGIC BLOCK DIAGRAM
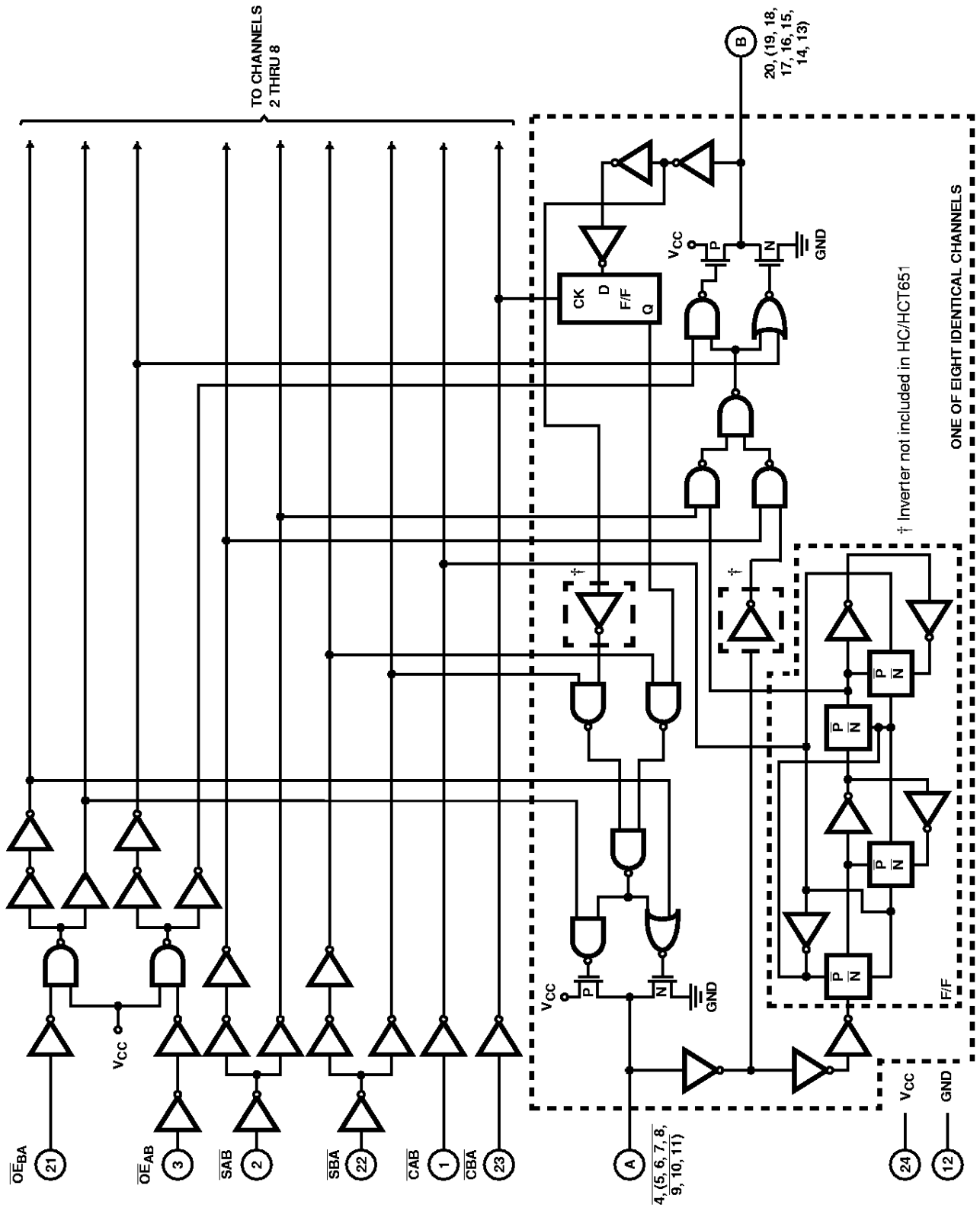
Absolute Maximum Ratings

DC Supply Voltage, V_{CC}
(Voltages Referenced to Ground) . . . . -0.5V to 7V
DC Input Diode Current, I_{IK}
For V_I < -0.5V or V_I > V_{CC} + 0.5V . . . . $\pm$20mA
DC Drain Current, I_O
For -0.5V < V_O < V_{CC} + 0.5V . . . . $\pm$35mA
DC Output Diode Current, I_{OK}
For V_O < -0.5V or V_O > V_{CC} + 0.5V . . . . $\pm$20mA
DC Output Source or Sink Current per Output Pin, I_O
For V_O > -0.5V or V_O < V_{CC} + 0.5V . . . . $\pm$25mA
DC V_{CC} or Ground Current, I_{CC} . . . . $\pm$50mA

Thermal Information

Thermal Resistance (Typical, Note 6) θ_{JA} (^{O}C/W)
  PDIP Package   75
  SOIC Package   75
Maximum Junction Temperature (Hermetic Package or Die) . . . 175°C
Maximum Junction Temperature (Plastic Package) . . . . 150°C
Maximum Storage Temperature Range . . . . -65°C to 150°C
Maximum Lead Temperature (Soldering 10s) . . . . 300°C
  (SOIC - Lead Tips Only)

Operating Conditions

Temperature Range, T_A . . . . -55°C to 125°C
Supply Voltage Range, V_{CC}
  HC Types . . . . .2V to 6V
  HCT Types . . . . .4.5V to 5.5V
DC Input or Output Voltage, V_I, V_O . . . . 0V to V_{CC}
Input Rise and Fall Time
  2V . . . . 1000ns (Max)
  4.5V . . . . 500ns (Max)
  6V . . . . 400ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

6. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

DC Electrical Specifications

PARAMETER	SYMBOL	TEST CONDITIONS V_I (V)	V_{IS} (V)	V_{CC} (V)	25°C MIN	TYP	MAX	-40°C TO 85°C MIN	MAX	-55°C TO 125°C MIN	MAX	UNITS
HC TYPES												
High Level Input Voltage	V_{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input Voltage	V_{IL}	-	-	2	-	-	0.3	-	0.3	-	0.3	V
				4.5	-	-	0.9	-	0.9	-	0.9	V
				6	-	-	1.2	-	1.2	-	1.2	V
High Level Output Voltage CMOS Loads	V_{OH}	V_{IH} or V_{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output Voltage TTL Loads		-	-	-	-	-	-	-	-	-	-	V
			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
			-7.8	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output Voltage CMOS Loads	V_{OL}	V_{IH} or V_{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads		-	-	-	-	-	-	-	-	-	-	V
			6	4.5	-	-	0.26	-	0.33	-	0.4	V
			7.8	6	-	-	0.26	-	0.33	-	0.4	V

CD74HC652, CD74HCT652

DC Electrical Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS			25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V_I (V)	V_{IS} (V)	V_{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Input Leakage Current	I_I	V_{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	µA
Quiescent Device Current	I_{CC}	V_{CC} or GND	0	6	-	-	8	-	80	-	160	µA
Three- State Leakage Current	V_{IL} or V_{IH}	$V_O =$ V_{CC} or GND	-	6	-	-	±0.5	-	±5.0	-	±10	µA
HCT TYPES												
High Level Input Voltage	V_{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V_{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V_{OH}	V_{IH} or V_{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V_{OL}	V_{IH} or V_{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I_I	V_{CC} and GND	0	5.5	-	-	±0.1	-	±1	-	±1	µA
Quiescent Device Current	I_{CC}	V_{CC} or GND	0	5.5	-	-	8	-	80	-	160	µA
Three- State Leakage Current	V_{IL} or V_{IH}	$V_O =$ V_{CC} or GND	-	5.5	-	-	±0.5	-	±5.0	-	±10	µA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI_{CC}	V_{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	µA

NOTE: For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
$\overline{OE}_{BA}$	1.3
OE_{AB}	0.75
Clock A to B, B to A	0.6
Select A, Select B	0.45
Inputs A_0-A_7, B_0-B_7	0.3

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at 25°C.

Prerequisite for Switching Specifications

PARAMETER	SYMBOL	V_{CC} (V)	25°C MIN	25°C TYP	25°C MAX	-40°C TO 85°C MIN	-40°C TO 85°C TYP	-40°C TO 85°C MAX	-55°C TO 125°C MIN	-55°C TO 125°C TYP	-55°C TO 125°C MAX	UNITS
HC TYPES												
Maximum Clock Frequency	f_{MAX}	2	6	-	-	5	-	-	4	-	-	MHz
		4.5	30	-	-	25	-	-	20	-	-	MHz
		6	35	-	-	29	-	-	23	-	-	MHz
Setup Time Data to Clock	t_{SU}	2	60	-	-	75	-	-	90	-	-	ns
		4.5	12	-	-	15	-	-	18	-	-	ns
		6	10	-	-	13	-	-	15	-	-	ns
Hold Time Data to Clock	t_H	2	35	-	-	45	-	-	55	-	-	ns
		4.5	7	-	-	9	-	-	11	-	-	ns
		6	6	-	-	8	-	-	9	-	-	ns
Clock Pulse Width	t_W	2	80	-	-	100	-	-	120	-	-	ns
		4.5	16	-	-	20	-	-	24	-	-	ns
		6	14	-	-	17	-	-	20	-	-	ns
HCT TYPES												
Maximum Clock Frequency	f_{MAX}	4.5	25	-	-	20	-	-	17	-	-	MHz
Setup Time Data to Clock	t_{SU}	4.5	12	-	-	15	-	-	18	-	-	ns
Hold Time Data to Clock	t_H	4.5	5	-	-	5	-	-	5	-	-	ns
Clock Pulse Width	t_W	4.5	25	-	-	31	-	-	38	-	-	ns

Switching Specifications Input t_r, t_f = 6ns

PARAMETER	SYMBOL	TEST CONDITIONS	V_{CC} (V)	25°C MIN	25°C TYP	25°C MAX	-40°C TO 85°C MIN	-40°C TO 85°C MAX	-55°C TO 125°C MIN	-55°C TO 125°C MAX	UNITS
HC TYPES											
Propagation Delay, Store A Data to B Bus Store B Data to A Bus	t_{PLH}, t_{PHL}	C_L = 50pF	2	-	-	220	-	275	-	300	ns
			4.5	-	-	44	-	55	-	66	ns
			6	-	-	37	-	47	-	5.6	ns
		C_L = 15pF	5	-	18	-	-	-	-	-	ns
Propagation Delay, A Data to B Bus B Data to A Bus	t_{PLH}, t_{PHL}	C_L = 50pF	2	-	-	135	-	170	-	205	ns
			4.5	-	-	27	-	34	-	41	ns
			6	-	-	23	-	29	-	35	ns
		C_L = 15pF	5	-	12	-	-	-	-	-	ns
Propagation Delay, Select to Data	t_{PLH}, t_{PHL}	C_L = 50pF	2	-	-	170	-	215	-	255	ns
			4.5	-	-	34	-	43	-	51	ns
			6	-	-	29	-	37	-	43	ns
		C_L = 15pF	5	-	14	-	-	-	-	-	ns

Switching Specifications Input t_r, t_f = 6ns **(Continued)**

| PARAMETER	SYMBOL	TEST CONDITIONS	V_{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Three-State Disabling Time Bus to Output or Register to Output	t_{PLZ}, t_{PHZ}	C_L = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
			6	-	-	30	-	37	-	45	ns
		C_L = 15pF	5	-	14	-	-	-	-	-	ns
Three-State Enabling Time Bus to Output or Register to Output	t_{PZL}, t_{PZH}	C_L = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
			6	-	-	30	-	37	-	45	ns
		C_L = 15pF	5	-	14	-	-	-	-	-	ns
Output Transition Time	t_{TLH}, t_{THL}	C_L = 50pF	2	-	-	60	-	75	-	90	ns
			4.5	-	-	12	-	15	-	18	ns
			6	-	-	10	-	13	-	15	ns
Three-State Output Capacitance	C_O	-	-	-	-	20	-	20	-	20	pF
Input Capacitance	C_I	-	-	-	-	10	-	10	-	10	pF
Maximum Frequency	f_{MAX}	C_L = 15pF	5	-	60	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 7, 8)	C_{PD}	-	5	-	52	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay, Store A Data to B Bus Store B Data to A Bus	t_{PLH}, t_{PHL}	C_L = 50pF	4.5	-	-	44	-	55	-	66	ns
		C_L = 15pF	5	-	18	-	-	-	-	-	ns
Propagation Delay, A Data to B Bus B Data to A Bus	t_{PLH}, t_{PHL}	C_L = 50pF	4.5	-	-	37	-	46	-	56	ns
		C_L = 15pF	5	-	15	-	-	-	-	-	ns
Propagation Delay, Select to Data	t_{PLH}, t_{PHL}	C_L = 50pF	4.5	-	-	46	-	58	-	69	ns
		C_L = 15pF	5	-	19	-	-	-	-	-	ns
Three-State Disabling Time Bus to Output or Register to Output	t_{PLZ}, t_{PHZ}	C_L = 50pF	4.5	-	-	35	-	44	-	53	ns
		C_L = 15pF	5	-	14	-	-	-	-	-	ns
Three-State Enabling Time Bus to Output or Register to Output	t_{PZL}, t_{PZH}	C_L = 50pF	4.5	-	-	45	-	56	-	68	ns
		C_L = 15pF	5	-	19	-	-	-	-	-	ns
Output Transition Time	t_{TLH}, t_{THL}	C_L = 50pF	4.5	-	-	12	-	15	-	18	ns
Three-State Output Capacitance	C_O	-	-	-	-	20	-	20	-	20	pF
Input Capacitance	C_I	-	-	-	-	10	-	10	-	10	pF
Maximum Frequency	f_{MAX}	C_L = 15pF	5	-	45	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 7, 8)	C_{PD}	-	5	-	52	-	-	-	-	-	pF

NOTES:

7. C_{PD} is used to determine the dynamic power consumption, per package.

8. $P_D = V_{CC}^2 C_{PD} f_i + \Sigma V_{CC}^2 C_L f_o$ where f_i = input frequency, f_o = output frequency, C_L = output load capacitance, C_S = switch capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms
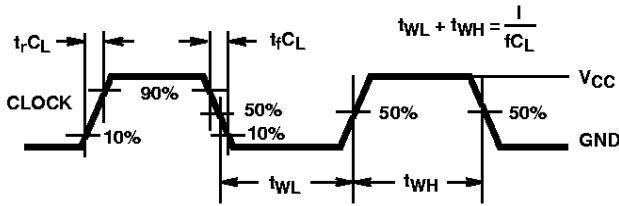
$t_{WL} + t_{WH} = \dfrac{1}{f_{CL}}$

NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX}, input duty cycle = 50%.

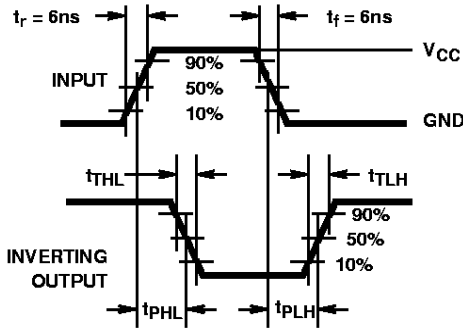FIGURE 2. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH
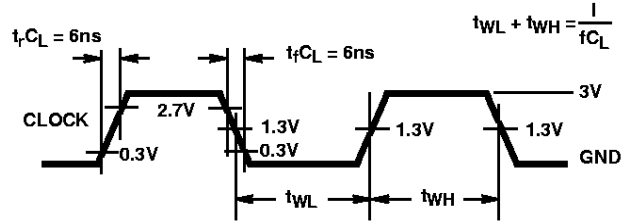
$t_{WL} + t_{WH} = \dfrac{1}{f_{CL}}$

NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX}, input duty cycle = 50%.

FIGURE 3. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

FIGURE 4. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC
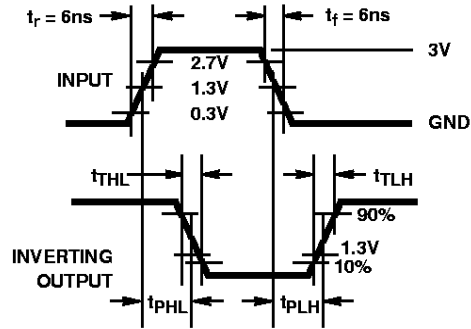
FIGURE 5. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC
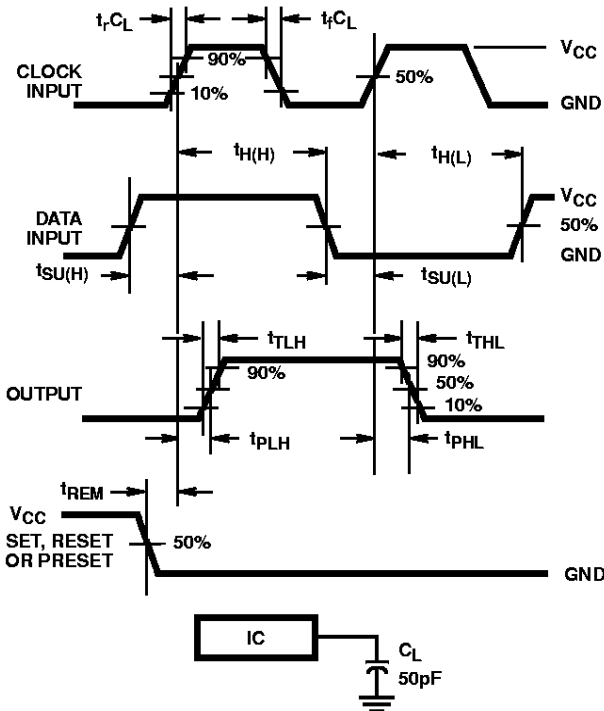
FIGURE 6. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS
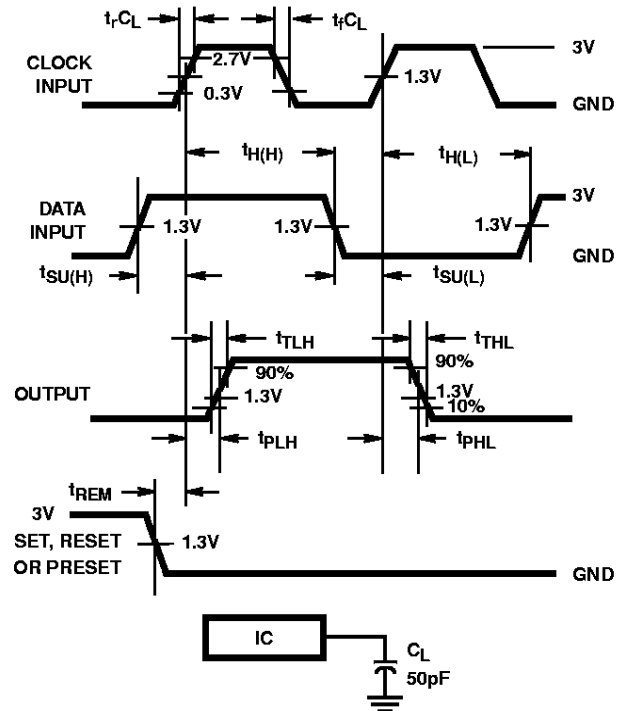
FIGURE 7. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

Test Circuits and Waveforms (Continued)
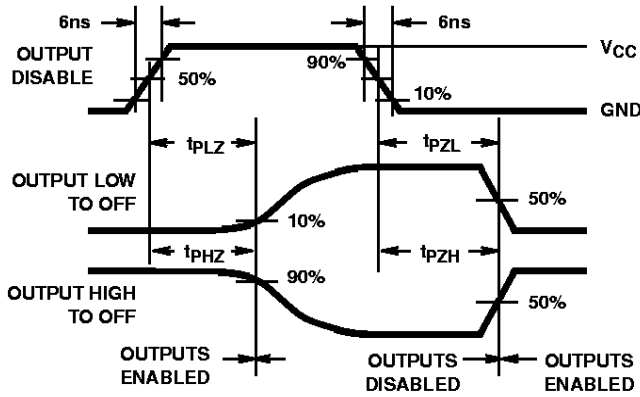
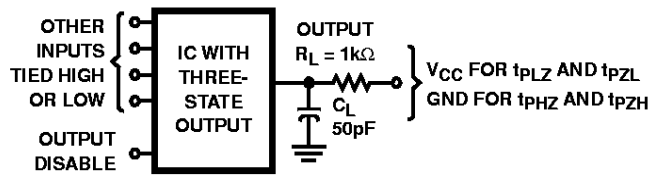**FIGURE 8. HC THREE-STATE PROPAGATION DELAY WAVEFORM**
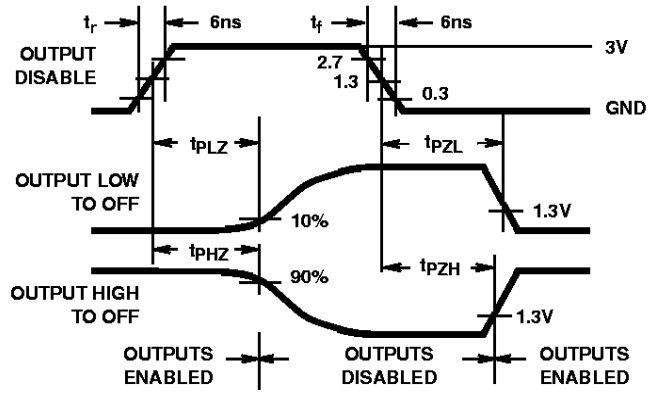
FIGURE 9. HCT THREE-STATE PROPAGATION DELAY WAVEFORM

NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output R_L = 1kΩ to V_{CC}, C_L = 50pF.

FIGURE 10. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

All Harris Semiconductor products are manufactured, assembled and tested under **ISO9000** quality systems certification.

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